NSN 5961-01-479-3549

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-479-3549 **Inclosure Material:** Glass **Overall Length:** Between 0.168 inches and 0.200 inches **Terminal Length:** Between 1.000 inches and 1.300 inches **Overall Diameter:** Between 0.065 inches and 0.110 inches Joint Electronic Device Engineering Council/jedec/case Outline Designation: D0-41 **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 600.0 working peak reverse voltage **Current Rating Per Characteristic:** 30.00 amperes forward current, average preset **Power Rating Per Characteristic:** 38.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Test Data Document:** 81349-mil-prf-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:**

Fiig: A110a0

Mil-std (military Standard):

Mil-prf-19500 spec.

Demilitarization:

No